



**PRM012N06N5**  
PFC Device Corporation

## 60V Single N-Channel MOSFET

### Major ratings and characteristics

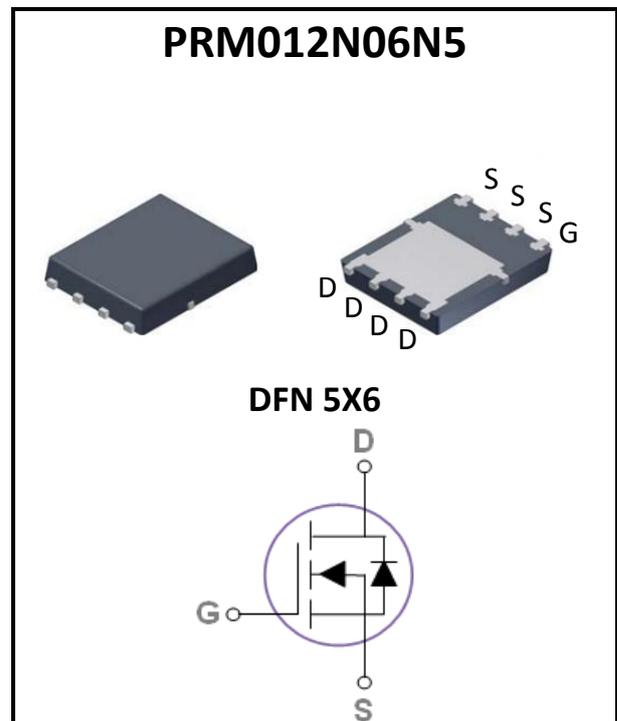
Characteristics	Values	Units
$V_{DS}$	60	V
$I_D$ ( $T_C=25^\circ\text{C}$ )	55	A
Max. $R_{DS(ON)}$	12	$\text{m}\Omega$
$T_J$ Operating Junction Temperature	-55 to +150	$^\circ\text{C}$

### General Description

The N-Channel enhancement mode power field effect transistor is using trench DMOS technology. This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. The device is well suited for high efficiency fast switching applications.

### Typical Applications

- Charger Adapter
- Power Tools
- LED Lighting



### Features

- Max.  $R_{DS(ON)}=12\text{m}\Omega@V_{GS}=10\text{V}$
- Improved  $dv/dt$  capability
- Fast switching
- 100%  $E_{AS}$  Guaranteed
- Green Device Available

## 1. Characteristics

### Maximum Ratings Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise specified )

Symbol	Parameter	Rating	Units
$V_{DS}$	Drain-Source Voltage	60	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current – Continuous ( $T_C=25^\circ\text{C}$ )	55	A
	Drain Current – Continuous ( $T_C=100^\circ\text{C}$ )	35	A
$I_{DM}$	Drain Current – Pulsed <sup>1</sup>	120	A
$E_{AS}$	Single Pulse Avalanche Energy <sup>2</sup>	34	mJ
$I_{AS}$	Single Pulse Avalanche Current <sup>2</sup>	26	A
$P_D$	Power Dissipation ( $T_C=25^\circ\text{C}$ )	69	W
	Power Dissipation – Derate above $25^\circ\text{C}$	0.55	W/ $^\circ\text{C}$
$T_{STG}$	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
$T_J$	Operating Junction Temperature Range	-55 to 150	$^\circ\text{C}$

### Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JA}$	Thermal Resistance Junction to ambient	---	62	$^\circ\text{C/W}$
$R_{\theta JC}$	Thermal Resistance Junction to Case	---	1.8	$^\circ\text{C/W}$



## Electrical Characteristics ( $T_J = 25^\circ\text{C}$ unless otherwise specified )

### Off Characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	60	---	---	V
$I_{DSS}$	Drain-Source Leakage Current	$V_{DS}=60V, V_{GS}=0V, T_J=25^\circ\text{C}$	---	---	1	$\mu A$
		$V_{DS}=60V, V_{GS}=0V, T_J=125^\circ\text{C}$	---	---	250	$\mu A$
$I_{GSS}$	Gate-Source Leakage Current	$V_{GS}=\pm 20V, V_{DS}=0V$	---	---	$\pm 100$	nA

### On Characteristics

$R_{DS(ON)}$	Static Drain-Source On-Resistance	$V_{GS}=10V, I_D=20A$	---	10	12	m $\Omega$
		$V_{GS}=4.5V, I_D=10A$	---	12	15	m $\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS}=V_{DS}, I_D=250\mu A$	1.0	1.6	3.0	V
$g_{fs}$	Forward Transconductance	$V_{DS}=5V, I_D=20A$	---	70	---	S

### Dynamic and switching Characteristics

$Q_g$	Total Gate Charge	$V_{DS}=30V, V_{GS}=10V, I_D=20A$	---	38	---	nC
$Q_{gs}$	Gate-Source Charge		---	7.5	---	
$Q_{gd}$	Gate-Drain Charge		---	7	---	
$T_{d(on)}$	Turn-On Delay Time	$V_{DD}=30V, V_{GS}=10V, R_G=6\Omega, I_D=20A$	---	15	---	ns
$T_r$	Turn-On Rise Time		---	85	---	
$T_{d(off)}$	Turn-Off Delay Time		---	41	---	
$T_f$	Turn-Off Fall Time		---	99	---	
$C_{iss}$	Input Capacitance	$V_{DS}=25V, V_{GS}=0V, f=1\text{MHz}$	---	2300	---	pF
$C_{oss}$	Output Capacitance		---	150	---	
$C_{rss}$	Reverse Transfer Capacitance		---	80	---	
$R_g$	Gate resistance	$V_{GS}=0V, V_{DS}=0V, f=1\text{MHz}$	---	2.1	---	$\Omega$

### Drain-Source Diode Characteristics

$V_{SD}^3$	Source to Drain Diode Voltage	$V_{GS}=0V, I_S=20A$	---	---	1.5	V
$t_{rr}$	Reverse Recovery Time	$I_S=20A, di/dt=100A/\mu s$	---	10	---	ns
$Q_{rr}$	Reverse Recovery Charge		---	1.5	---	nC

Note :

1. Repetitive Rating : Pulsed width limited by maximum junction temperature.
2.  $V_{DD}=50V, V_{GS}=10V, L=0.1\text{mH}, I_{AS}=26A, R_G=25\Omega, \text{Starting } T_J=25^\circ\text{C}$
3. The data tested by pulsed, pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$ .



2. Characteristics Curves

Ratings and Characteristics Curves

(  $T_A = 25^{\circ}\text{C}$  unless otherwise specified )

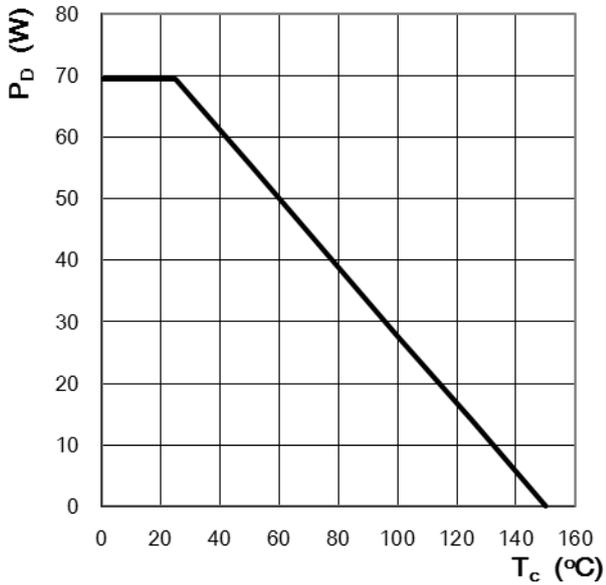


Figure 1: Power Dissipation

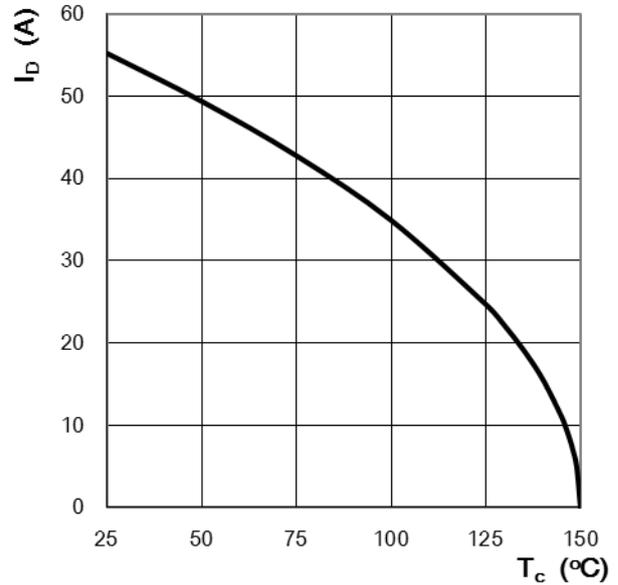


Figure 2: Continuous Drain Current vs.  $T_c$

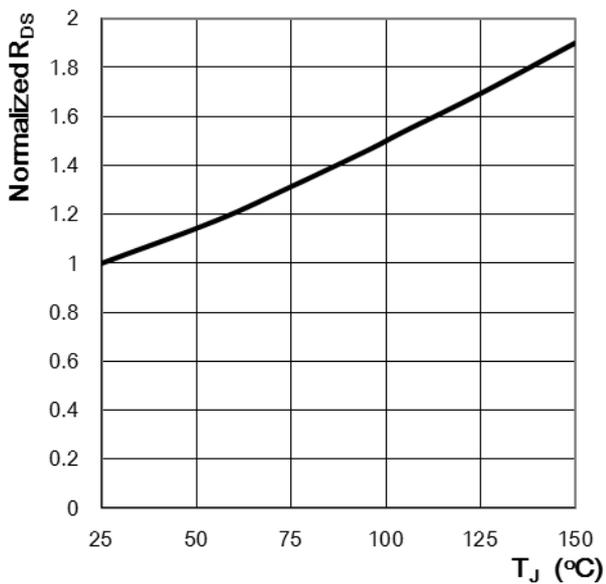


Figure 3: Normalized  $R_{DS(ON)}$  vs.  $T_J$

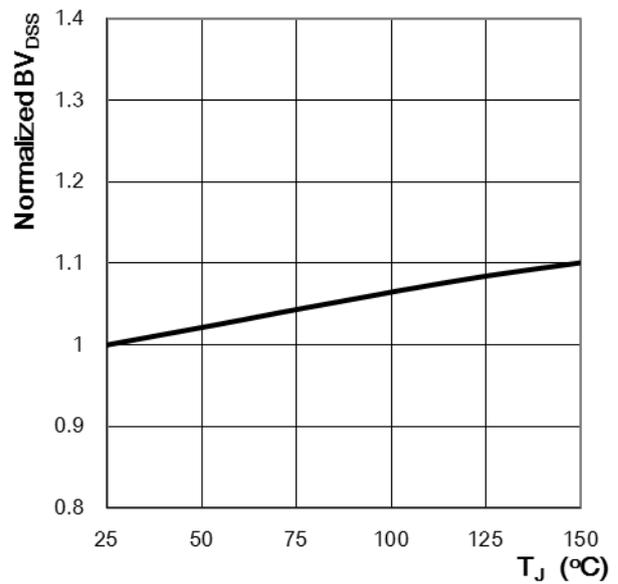


Figure 4: Normalized  $BV_{DSS}$  vs.  $T_J$



Ratings and Characteristics Curves

(  $T_A = 25^\circ\text{C}$  unless otherwise specified )

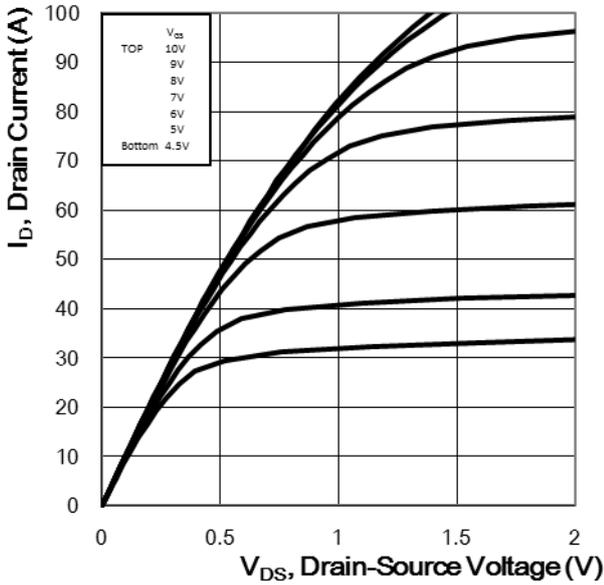


Figure 5: On-Region Characteristics

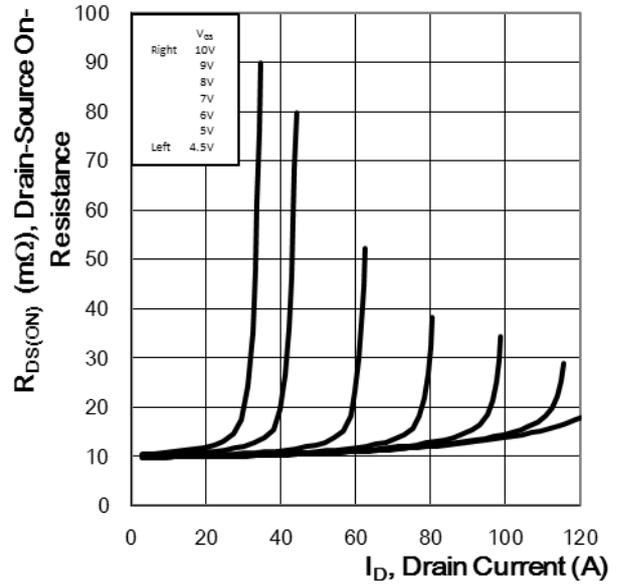


Figure 6: Typ.  $R_{DS}$  Variation vs.  $I_D$  and  $V_{GS}$

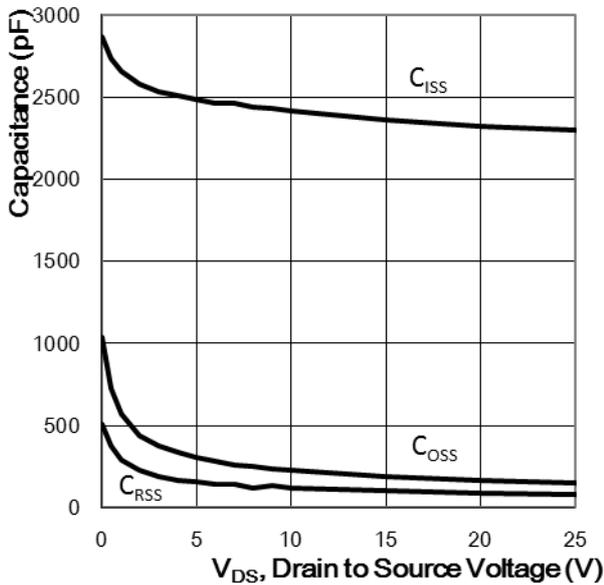


Figure 7: Typ. Capacitance Characteristics

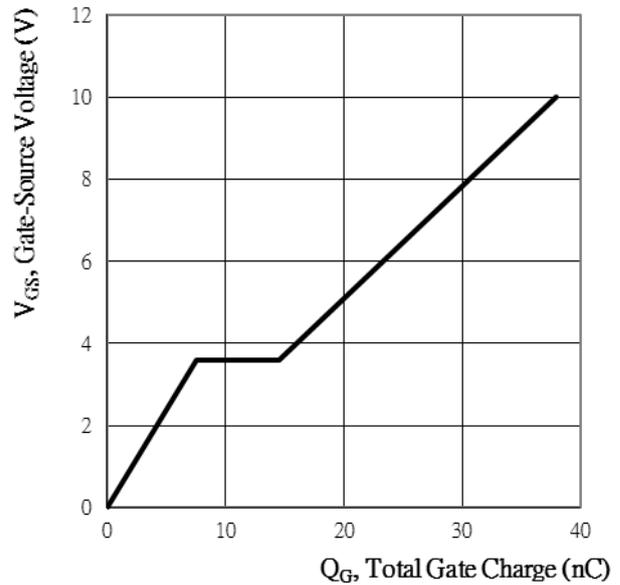


Figure 8: Typ. Gate Charge Characteristics



Ratings and Characteristics Curves (  $T_A = 25^\circ\text{C}$  unless otherwise specified )

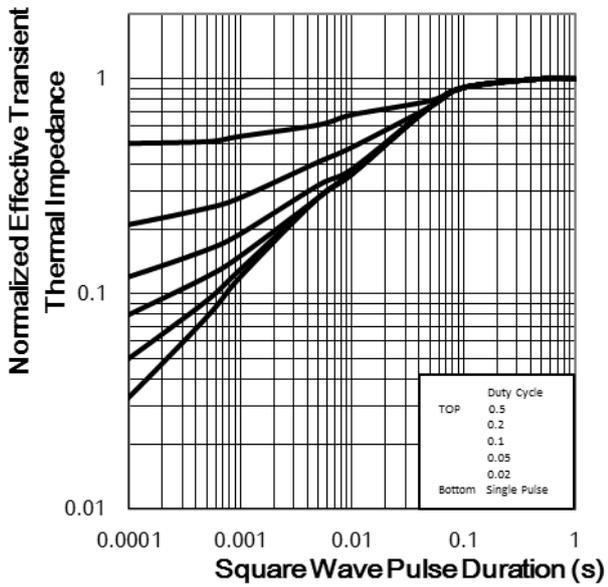


Figure 9: Normalized Thermal Transient Impedance, Junction-to-Case

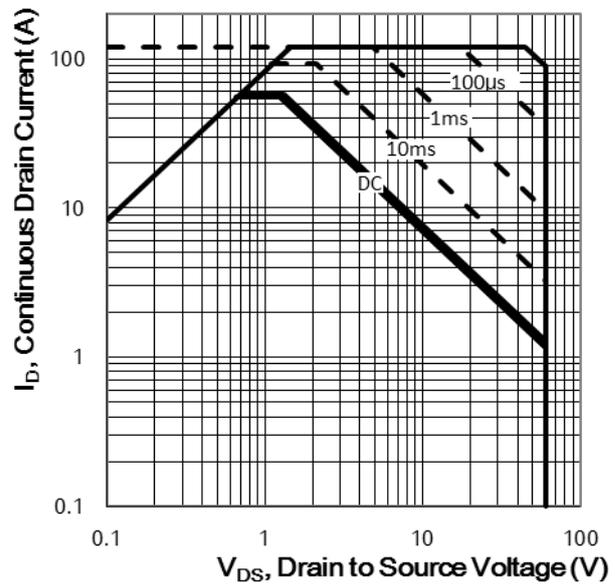
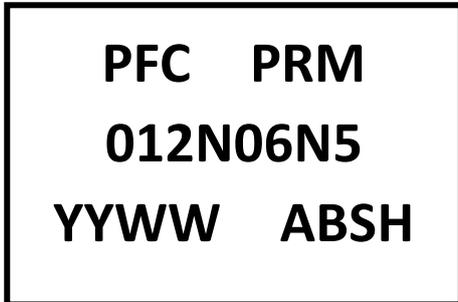


Figure 10: Maximum Safe Operation Area



**3. Marking information**

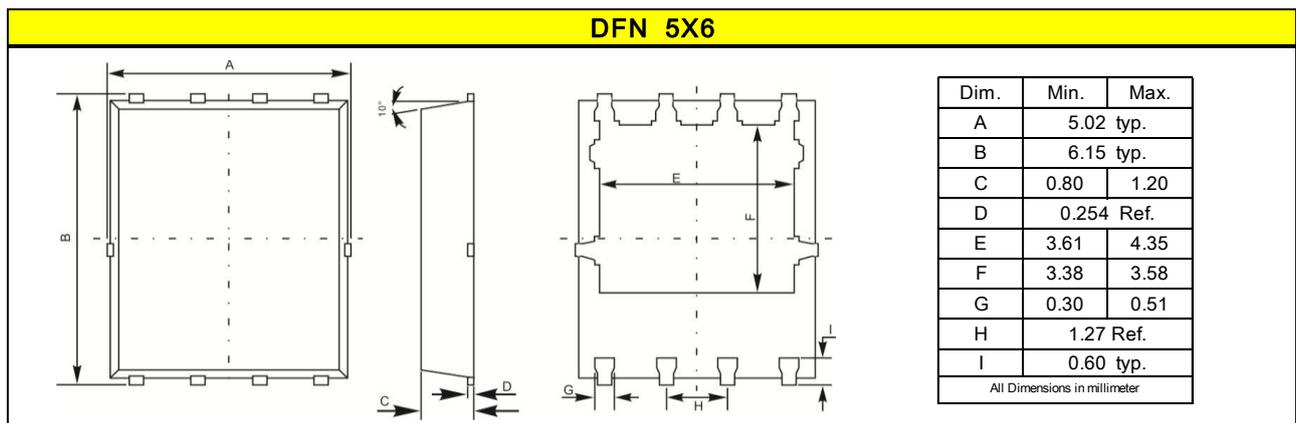
Top Marking Rule



PRM012N06N5 = Product Type Marking Code  
 YYWW = Date Code  
 YY = Last two digits of year  
 WW = Week code  
 ABS = Assembly code  
 H = Halogen Free (N/A = common molding compound)

**4. Package information**

Package Outline Dimensions millimeters



**5. Ordering information**

Part Number	Package	Delivery mode
PRM012N06N5	DFN 5X6	3000 pcs / 13" diameter reel

Mechanical

- Molder Plastic: UL Flammability Classification Rating 94V-0
- Device Weight : 0.003 ounces (0.093grams) – DFN 5X6

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